Phase Transition Lowering and Melting in Dynamically-Compressed Silicon and Germanium at the LCLS

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Despite being the subject of numerous shock compression studies, the behavior of silicon under dynamic loading is vigorously debated [1-4]. The few studies that combine shock compression and X-ray diffraction have exclusively focused on “normal” X-ray geometry whereby X-rays are collected along the shock propagation direction, consequently sampling numerous strain states at once, and hence greatly complicating both phase identification and studies of phase transition kinetics.[5] Here, we present a novel setup to perform in situ X-ray diffraction studies perpendicular to the shock propagation direction at the Matter in Extreme Conditions end station at Linac Coherent Light Source, SLAC. Combining the extremely bright, micro-focused X-ray beam available at the LCLS with a nanosecond laser driver, we unambiguously characterize of the complex multi-wave shock response in silicon for the first time. We further combine this platform for performing simultaneous imaging with X-ray diffraction from shock compressed germanium, revealing its behaviour following shock compression. We note the transverse geometry is significantly more sensitive to the onset of both solid-solid and solid-liquid phase transformations in materials which exhibit complex multi-wave behaviour, and compare and constrast the behaviour of Si and Ge.

[3] Colburn et al., JAP, 43, 5007 (1972)

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